# Thermal drag in capacitively-coupled metallic islands

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## Coulomb drag



## Two electrically isolated conductors



\* only upper conductor is biased
 \* current is dragged in lower if they are coupled via the
 Coulomb interaction (energy and momentum transfer)

- Iayered systems (2DEG, graphene)
- → 1D wires
- QH edge states

Review: Narozhny, Levchenko (2016)

## **Coulomb drag**



### > 0D, single-electron systems



sigle level QD, broken detail balance (energy-dependent lead couplings)

Sánchez, Lopez, Sánchez, Büttiker (2010) Moldoveanu, Tanatar (2009)

## Experiment, QD

#### # graphene-based QD

Volk et al. (2015) Bischoff et al. (2016)

#### Iithographically-patterned QD Keller et al. (2016)

**\*** cotunnelling is crucial Kaasbjerg, Jauho (2016)

National Enterprise for nanoScience and nanoTechnology





Keller et al. (2016)

## **Coulomb drag**



## Energy harvesting from thermal/voltage fluctuations, thermocouple heat engine Sánchez Büttiker (2011)



Sánchez, Büttiker (2011) Sothmann, Sánchez, Jordan, Büttiker (2012) Sánchez, Sothmann, Jordan, Büttiker (2013) Sothmann, Sánchez, Jordan (2015) Daré, Lombardo (2017) Whitney, Sánchez, Haupt, Splettstoesser (2016)

#### \* energy-dependence and asymmetry of lead coupling essential





Hartmann, Pfeffer, Höfling, Kamp, Wordchech (2015) Thierschmann, Arnold, Mittermüller, Maier, Heyn, Hansen, Buhmann, Molemkamp (2015)

## **Thermal drag**





\* Capacitively-coupled **metallic islands**, lead coupling energy-independent



Koski, Kutvonen, Khaymovich, Ala-Nissila, Pekola (2015)







- Coulomb-blockade regime
- \* Lead-island couplings are energy-independent
- Sequential tunneling
- Modragged charge current, even for

**Finite dragged heat** current for

 $\mathcal{R}_{L2} \neq \mathcal{R}_{\text{R2d} \, \text{Enterprise for nano} \textbf{S}_{\text{cience and nano} \textbf{T}_{\text{echnology}}}$ 



#### # Electrostatic energy

$$U(n_{1}, n_{2}) = E_{C,1} (n_{1} - n_{x_{1}})^{2} + E_{C,2} (n_{2} - n_{x_{2}})^{2} + E_{I} (n_{1} - n_{x_{1}}) (n_{2} - n_{x_{2}})$$

$$n_{x1} = V_{g1} \frac{C_{g}}{e}$$

$$n_{x2} = V_{g2} \frac{C_{g}}{e}$$
inter-island interaction energy controlled by  $C_{I}$ 

**\*** Electrostatic energy change for transitions in lower island

$$\delta U_2(n_1, n_2) = U(n_1, n_2 + 1) - U(n_1, n_2)$$

depends on the charge state in island 1



In Dragged heat current results from energy transferred from drive circuit, through this mechanism



 $\blacksquare$  Heat current associated to this processes:  $E_{I}$ 

Heat currents are modulated through gate voltages



 $\ensuremath{\ensuremath{\boxtimes}}$  Width independent of E<sub>1</sub>, but controlled by temperature  $\ensuremath{\boxtimes}$  Maximum occurs in the symmetric energy configuration



Sequential tunnelling, small bias

expansion in 
$$\Delta T/T$$
  
 $I_{\rm drag}^{(h)} = \frac{\xi \mathcal{R}_{\parallel}}{6e^2 \mathcal{R}} \left[ \frac{1}{\mathcal{R}_{\rm L2}} - \frac{1}{\mathcal{R}_{\rm R2}} \right] \operatorname{csch} \xi \left[ 2\xi \left( \frac{\pi^2}{4} + \xi^2 \right) \operatorname{csch} \xi - \left( \frac{\pi^2}{2} + 3\xi^2 \right) \operatorname{sech} \xi \right] (k_B \Delta T)^2$   
 $\overleftarrow{} Second order in \Delta T$   
 $\xi = \frac{E_{\rm I}}{4k_B T}$ 

#### expansion in $eV/E_C$

$$I_{\rm drag}^{\rm (h)} = \frac{\xi \mathcal{R}_{\parallel}}{16\mathcal{R}} \left[ \frac{1}{\mathcal{R}_{\rm L2}} - \frac{1}{\mathcal{R}_{\rm R2}} \right] \operatorname{csch} \xi \left[ \xi \operatorname{csch} \xi - \operatorname{sech} \xi \right] V^2$$

 $\ensuremath{\underline{\mathsf{S}}}$  Second order in V



## Sequential tunnelling, dependence on inter-island coupling



thin curves ---> analytical
thick curves ---> numerical

 $I_0^{(\mathrm{h})} = e^2 / (4C^2 \mathcal{R})$ 

 $E_{\rm I}^{\rm max} \simeq 8.5 k_B T$  $E_{\rm I}^{\rm max} \simeq 5.5 k_B T$ 

Image: Deviation due to T not small

- Sequential tunnelling, drag-drive comparison
  - **I** Temperature-biased case:  $I_{R2}^{(h)} < I_{R1}^{(h)}$
- $\blacksquare$  Voltage-biased case:  $I_{R2}^{(h)} > I_{R1}^{(h)}$











Cotunnelling contributions, large bias





**Solution** Non-trivial contributions **Solution** Quadratic dependence on V and  $\Delta T$ 



## Energy-dependent couplings: superconductor





#### Finite dragged charge



## Conclusions



> Thermal drag in capacitively-coupled metallic islands

Sequential tunneling regime
Co-tunneling contributions

\* Analytic expressions for heat currents for <u>small</u> <u>biases</u>

**\*** Dependence on the inter-islands coupling

# Energy-Dependent island-lead couplings